

arXiv:1109.1445v1 [cond-mat.mes-hall]

## Mechanically probing coherent tunnelling in a double quantum dot

J. Gardner<sup>1</sup> and A. A. Clerk<sup>1</sup>

<sup>1</sup>*Department of Physics, McGill University, Montréal, Québec, Canada H3A 2T8*

(Dated: Sept. 7, 2011)

We study theoretically the interaction between the charge dynamics of a few-electron double quantum dot and a capacitively-coupled AFM cantilever, a setup realized in several recent experiments. We demonstrate that the dot-induced frequency shift and damping of the cantilever can be used as a sensitive probe of coherent inter-dot tunnelling, and that these effects can be used to quantitatively extract both the magnitude of the coherent interdot tunneling and (in some cases) the value of the double-dot  $T_1$  time. We also show how the adiabatic modulation of the double-dot eigenstates by the cantilever motion leads to new effects compared to the single-dot case.

# Introduction

- ▶ Applications of QDs both for QI and as a laboratory for studies of fundamental physics.
- ▶ Self-assembled, epitaxial QDs have advantages over lithographically defined dots: size, confinement, scalability.
- ▶ Direct electrical characterization (transport exp.) difficult due to their small size.
- ▶ Alternative approach using an AFM, which couples capacitively to the QD charge. The QD dynamics alters the frequency and the damping rate of the cantilever.
- ▶ It provides informations on the QD.

## Proposal:

- ▶ Consider a low-frequency cantilever coupled to a double QD.
- ▶ Investigate the dependence to the strength of the coherent tunneling between the QDs.
- ▶ Results are derived using a linear-response, quantum master-equation calculation. (In extent to the often used semi-classical Fokker-Planck treatment)

## New Effects

- ▶ In the vicinity of the charge transfer line (*almost degenerate DQD configurations with the same total charge*), new mechanism for the DQD-induced cantilever damping, that is enhanced by the relatively long charge relaxation.  
→ Characterization of  $T_1$  time of the DQD.
- ▶ Another new mechanism for the DQD-induced cantilever frequency shift near the charge transfer line. Due to coherent tunneling, the DQD energy eigenstates are superpositions of charge states. The cantilever motion could adiabatically modulate these wavefunctions.  
→ Allows to probe the interdot tunneling.

## Model

- ▶ A self-assembled DQD capacitively coupled to an oscillating metallic cantilever is considered. The dots are also tunnel-coupled to a 2DEG.
- ▶ Coulomb blockade Hamiltonian with coherent interdot tunneling.

$$\hat{H}_{DQD} = \hat{H}_c + t_c \left( \hat{d}_L^\dagger \hat{d}_R + \hat{d}_R^\dagger \hat{d}_L \right) + \hat{H}_{res},$$
$$\hat{H}_c = \sum_{\alpha=L,R} E_{C\alpha} (\hat{n}_\alpha - \mathcal{N}_\alpha)^2 + E_{Cm} (\hat{n}_L - \mathcal{N}_L) (\hat{n}_R - \mathcal{N}_R)$$

$\hat{H}_{res}$  describes a free 2DEG and dot-2DEG tunneling.

- ▶ Assumptions:
  - ▶ spinless electrons
  - ▶ few-electron regime (at most one electron per dot), only a single orbital in each dot is retained.
  - ▶ Coulomb blockade regime  $E_{C\alpha} \gg k_B T$
  - ▶ 2DEG in equilibrium at  $T$
  - ▶ dot-2DEG tunnel matrix element is the same for both dots. ( $\sim \Gamma$ )

- ▶ The dimensionless gate voltages  $\mathcal{N}_\alpha$  depend on the cantilever position  $\vec{r}_{tip}$ ,

$$\mathcal{N}_\alpha = -\frac{V_B C_{tip,\alpha} (|\vec{r}_{tip} - \vec{r}_\alpha|)}{e}, \quad (C_{tip,\alpha} : \text{cantilever-dot capacitance})$$

- ▶ Letting the cantilever height  $z_m$  oscillate. The coordinate  $z_m$  is described as an harmonic oscillator with frequency  $\omega_m$  and mass  $m$ . Considering small oscillations, the dependence of  $\mathcal{N}_\alpha$  is linearized in  $z_m$ . The DQD-cantilever interaction is

$$\hat{H}_{int} = -\hat{z}_m \sum_{\alpha=L,R} A_\alpha \hat{n}_\alpha \equiv -\hat{z}_m \hat{F},$$

$$A_\alpha = 2E_{C\alpha} \frac{\partial \mathcal{N}_\alpha}{\partial z_m} + E_{Cm} \frac{\partial \mathcal{N}_{\bar{\alpha}}}{\partial z_m} = -\frac{\partial E_{+\alpha}}{\partial z_m}.$$

Electron addition energy:  $E_{+\alpha} = E_{C\alpha}(1 - 2\mathcal{N}_\alpha) - E_{Cm}\mathcal{N}_{\bar{\alpha}}$ .

- ▶ Mostly focus on the regime where the total DQD charge is fixed at 1 and where  $\delta = \frac{E_{+L} - E_{+R}}{2}$  is small (electrostatic energy detuning between state  $|01\rangle$  and  $|10\rangle$ .) States with  $\hat{n}_{tot} > 2$  can be neglected.
- ▶ In self-assembled QDs,  $t_c \gg \Gamma, \omega_m$  is satisfied and it is useful to work in the basis of adiabatic eigenstates of  $\hat{H}_{DQD}$ , determined by the instantaneous value of  $z_m$ .

$$\begin{aligned}
 |1[z_m]\rangle &= |11\rangle, & |2[z_m]\rangle &= -\sin(\theta/2)|10\rangle + \cos(\theta/2)|01\rangle, \\
 |3[z_m]\rangle &= \cos(\theta/2)|10\rangle + \sin(\theta/2)|01\rangle, & |4[z_m]\rangle &= |00\rangle,
 \end{aligned}$$

where  $\tan \theta[z_m] = t_c / \delta[z_m] = t_c / (\delta - \frac{1}{2}z_m(A_L - A_R))$ . Adiabatic eigenenergies,

$$\begin{aligned}
 E_{2,3}[z_m] &= \left( \frac{E_{+L} + E_{+R} - z_m(A_L + A_R)}{2} \right) \mp \sqrt{(\delta[z_m])^2 + t_c^2} \\
 &\equiv \varepsilon[z_m] \mp \Delta[z_m].
 \end{aligned}$$

- ▶ For  $z_m = 0$ , the states  $|2\rangle$  and  $|3\rangle$  will primarily be occupied by the DQD. Approximately the physics of a two-level system.

## Calculation

- ▶ Because of the DQD-cantilever coupling  $\hat{H}_{int} = -\hat{z}_m \hat{F}$ , the average force  $\langle \hat{F} \rangle$  will respond with a delay to the motion of the oscillator resulting in both a spring-constant shift  $k_{dot}$  and extra damping  $\gamma_{dot}$ .
- ▶ In the weak coupling limit, it is well described within linear response.  $k_{dot}$  and  $\gamma_{dot}$  are calculated by replacing  $\hat{z}_m \rightarrow z_m(t) = z_0 \cos(\omega_m t)$ .
- ▶ A Lindblad master equation is derived to describe these effects in the regime  $\omega_m \ll T$ .

$$\frac{\partial \hat{\rho}_{rot}}{\partial t} = \frac{1}{i\hbar} [\hat{H}_{eff}, \hat{\rho}_{rot}] + \sum_{j,k=1}^4 \Gamma_{jk} \mathcal{D}[\hat{S}_{jk}] \hat{\rho}_{rot},$$

$$\hat{H}_{eff} = \varepsilon \hat{n}_{tot} + E_m |4\rangle \langle 4| + \Delta \hat{\sigma}_z - \frac{\hbar}{2} \frac{\partial z_m}{\partial t} \frac{\partial \theta}{\partial z_m} \hat{\sigma}_y,$$

$$\mathcal{D}[\hat{S}_{jk}] \hat{\rho}_{rot} = \hat{S}_{jk} \hat{\rho}_{rot} \hat{S}_{jk}^\dagger - \frac{1}{2} (\hat{S}_{jk}^\dagger \hat{S}_{jk} \hat{\rho}_{rot} + \hat{\rho}_{rot} \hat{S}_{jk}^\dagger \hat{S}_{jk}), \quad \hat{S}_{jk} = |j\rangle \langle k|$$

where

$$\hat{\rho}_{rot}(t) = \hat{U}[z_m(z)]^\dagger \hat{\rho}(t) \hat{U}[z_m(z)] \quad \text{and} \quad \hat{U}[x] |j[0]\rangle = |j[x]\rangle,$$

$$\hat{\sigma}_z = |3\rangle \langle 3| - |2\rangle \langle 2|, \quad \hat{\sigma}_y = i(|2\rangle \langle 3| - |3\rangle \langle 2|).$$

To obtain  $k_{dot}$  and  $\gamma_{dot}$ , the ME is used to find the first-order-correction to  $\hat{\rho}_{rot}$  in  $z$  and calculate the corresponding change in  $\langle \hat{F}(t) \rangle$  to infer  $k_{dot}$  and  $\gamma_{dot}$ .

## Basic Mechanisms

- ▶ Low-frequency limit, the linear response results have the form:

$$m\gamma_{dot} = \tau \frac{\partial \langle \hat{F} \rangle}{\partial z_m}, \quad k_{dot} = -\frac{\partial \langle \hat{F} \rangle}{\partial z_m}.$$

- ▶ Single dot case  $\frac{\partial \langle \hat{F} \rangle}{\partial z_m} \propto \frac{\partial \langle \hat{n}_{tot} \rangle}{\partial \mathcal{N}}$ , thus  $\gamma_{dot}$  and  $k_{dot}$  are only significant when the QD total charge can fluctuate via 2DEG-QD tunneling (charge addition lines).
- ▶ In the DQD case,  $\gamma_{dot}$  and  $k_{dot}$  are determined by the dynamics of the DQD charge distribution.
- ▶ Near the charge transfer line, the DQD-induced force operator is

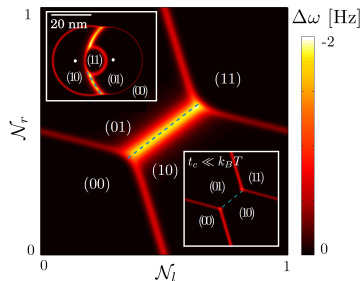
$$\hat{F} - \frac{A_L + A_R}{2} \simeq A_\delta (\hat{n}_L - \hat{n}_R) = A_\delta (\cos \theta \hat{\sigma}_z - \sin \theta \hat{\sigma}_x), \quad A_\delta = \frac{A_L - A_R}{2}.$$

- ▶ Three different mechanisms :  $\partial_{z_m} \langle \hat{\sigma}_x \rangle$ ,  $\partial_{z_m} \langle \hat{\sigma}_z \rangle$  and  $\partial_{z_m} \theta$ . The first is strongly suppressed as  $\omega_m \ll t_c$ .



# Adiabatic Frequency Shift

- ▶  $\hat{F}$  has a dependence on  $\theta$ , which has an intrinsic  $z_m$ -dependence, causing a modulation of  $\hat{F}$ .
- ▶ It corresponds to the adiabatic modulation of the DQD eigenstates by the cantilever oscillation, via the cantilever's modulation of the electrostatic detuning  $\delta$ .
- ▶ The corresponding oscillation in  $\langle \hat{n}_L - \hat{n}_R \rangle$  causes a force oscillation, in phase with  $z_m(t)$ .



$$\Delta\omega = k_{dot}/(2m\omega_m)$$

$\omega_m = 160 \text{ kHz}, k_0 = 7 \text{ N/m},$   
 $\Gamma = 10 \text{ kHz}, T = 4.2 \text{ K},$   
 $t_c = 1 \text{ meV}, E_{CL} = 20 \text{ meV},$   
 $E_{CR} = 25 \text{ meV}, E_{Cm} = 12 \text{ meV}.$

$$k_{dot} = -A_\delta \langle \hat{\sigma}_z \rangle \frac{\partial \cos \theta}{\partial z_m} = -\frac{A_\delta^2 \sin^2 \theta \tanh(\Delta/k_B T)}{\Delta}.$$

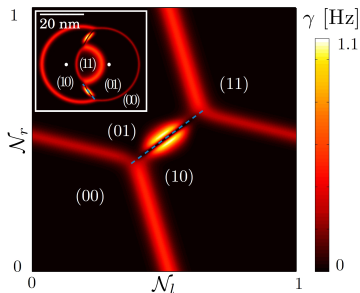
## Effective TLS Damping

- ▶ Second mechanism near the charge transfer line: the cantilever's modulation of  $\langle \hat{\sigma}_z \rangle$ , that is the population asymmetry of the two low-energy DQD eigenstates.
- ▶ The DQD splitting  $\Delta$  oscillates due to the cantilever oscillations. Thus the occupancy of the states  $|2\rangle$  and  $|3\rangle$  also oscillates.
- ▶ The corresponding oscillations in  $\langle \hat{\sigma}_z \rangle$ , hence in  $\langle \hat{F} \rangle$ , are phase-shifted with respect to  $z_m(t)$  due to the finite DQD  $T_1$  time.
- ▶ This mechanism contributes both to  $k_{dot}$  and  $\gamma_{dot}$  and is suppressed at low temperatures  $T \ll \Delta$ .
- ▶ DQD-induced damping

$$m\gamma_{dot} = \left( \frac{T_1}{1 + \omega_m^2 T_1^2} \right) \frac{A_\delta^2 \cos^2 \theta}{k_B T \cosh^2(\Delta/k_B T)}$$

## Dot-induced Damping

- ▶ Dot-induced damping not only occurs near the charge addition lines, where DQD-2DEG tunneling is strong. ( $\gamma_{dot} \propto 1/\Gamma$ )
- ▶ For low frequency cantilever, near charge transfer line,  $\gamma_{dot} \propto T_1$ .
- ▶ If  $T_1\Gamma > 1$ , the "TLS damping" mechanism can be greater in magnitude than the conventional damping peaks found near charge addition lines.
- ▶ This effect vanishes at  $\delta = 0$  due to the presence of coherent tunneling.



$$\begin{aligned}\omega_m &= 75 \text{ kHz}, k_0 = 3 \text{ N/m}, \\ \Gamma &= 10 \text{ MHz}, T = 8.4 \text{ K}, \\ t_c &= 0.3 \text{ meV}, E_{CL} = 20 \text{ meV}, \\ E_{CR} &= 25 \text{ meV}, E_{Cm} = 12 \text{ meV}.\end{aligned}$$

## Measuring $T_1$

- ▶ For low frequency cantilever and  $T \gg \Delta$ ,
- ▶ near the charge transfer line

$$\frac{m\dot{\gamma}}{k_{dot}} \simeq -\cos^2 \theta T_1.$$

- ▶ Allows direct measure of the DQD  $T_1$  time.

## Conclusion

- ▶ Charge dynamics in DQD can influence damping and frequency shifts of a low-frequency resonator (AFM tip).
- ▶ Compared to single QD, qualitatively new effects arise due to the cantilever's sensitivity to charge distribution and to the presence of coherent interdot tunneling.
- ▶ These effects allow to access the DQD  $T_1$  time near the charge transfer line and to probe the strength of the coherent tunneling.